

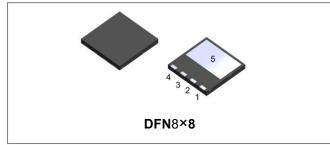
Data Sheet N2440, REV.-

Technical Data

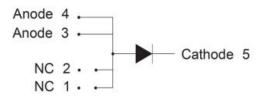
S3D03065L



S3D03065L 650V SIC POWER SCHOTTKY RECTIFIER



Circuit Diagram



Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

Maximum Ratings

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	-	650	V
	I _{F (AV)1}	Tc=25°C	17	А
Average Rectified Forward Current	IF (AV)2	Tc=136°C	8	А
	I _{F (AV)3}	Tc=157°C	3	A
	I _{FRM1}	10ms, Half Sine pulse, T _C =25°C	23	А
Repetitive Peak Forward Surge Current	I _{FRM2}	10ms, Half Sine pulse, T _c =110°C	15	A
	I _{FSM1}	10ms, Half Sine pulse, T _C =25°C	46	A
Peak One Cycle Non-Repetitive Surge Current	I _{FSM2}	10ms, Half Sine pulse, T _C =110°C	23	А
Non-Repetitive Peak Forward Surge Current	I _{F,Max1}	10µs. Pulse, Tc =25℃	390	А
Non-Repetitive Fear Forward Surge Current	I _{F,Max2}	10µs. Pulse, T _C =110°C	265	А
	P _{tot1}	T _C =25℃	60	W
Power Dissipation	P _{tot2}	T _c =110°C	26	W

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Description

S3D03065L is a SiC Schottky rectifier packaged in DFN8×8 case. The device is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D03065L is ideal for energy sensitive, high frequency applications in challenging environments.

Features

- 175°C T_J operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request



Technical Data Data Sheet N2440, REV.-

Electrical Characteristics:



Electrical Characteristics:					
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 3A, Pulse, T _J = 25 °C	1.4	1.7	V
-	V _{F2}	@ 3A, Pulse, T _J = 175 °C	1.6	2.0	V
Reverse Current*	I _{R1}	$@V_R = rated V_R$ T _J = 25 °C	0.03	2	uA
	I _{R2}	@V _R = rated V _R T _J = 175 ℃	0.3	20	uA
Junction Capacitance	Ст	V _R =0V, T _J =25℃, f=1MHz	230	-	pF
Reverse Recovery Charge	Qc	I _F = 3A, di/dt = 200A/μs VR = 400 V, T _J =25°C	14.35	-	nC
Capacitance Stored Energy	Ec	V _R = 400 V, T _J =25°C	3.51	-	μJ

* Pulse width < 300 $\mu s, \ duty \ cycle < 2\%$

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R ₀ JC	DC operation	2.5	°C/W

Marking Diagram



Where XXXXX is YYWWL

S3D	= Device Type
L	= Package type
03	= Forward Current (3A)
065	= Reverse Voltage (650V)
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping
S3D03065L	DFN 8×8	3000/Reel
S3D03065LTR	DFN 8×8	3000/Reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging Specification.

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S3D03065L



Ratings and Characteristics Curves

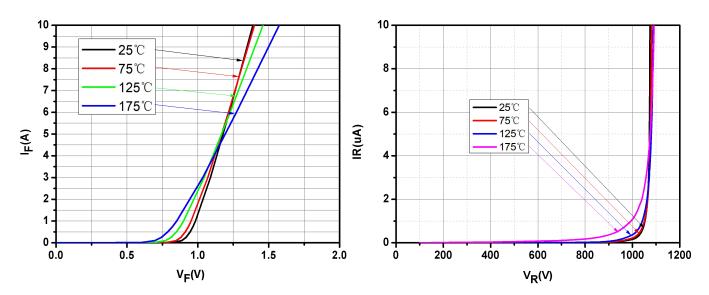


Fig.1-Typical Forward Voltage Characteristics

Fig.2-Typical Reverse Characteristics

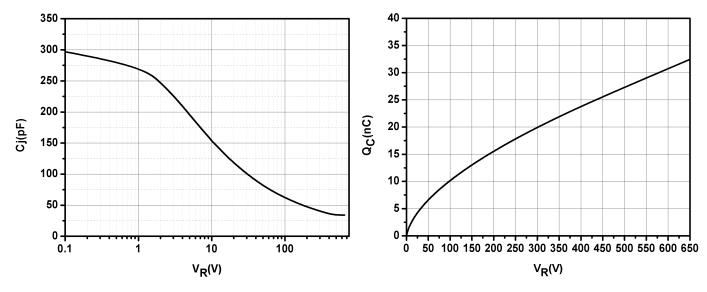


Fig.3-Capacitance vs. Reverse Voltage

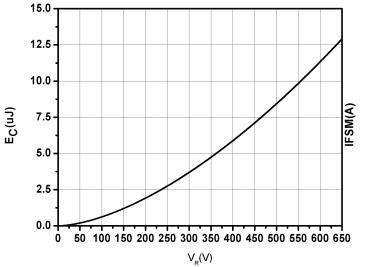
Fig.4-Total Capacitance Charge vs. Reverse Voltage

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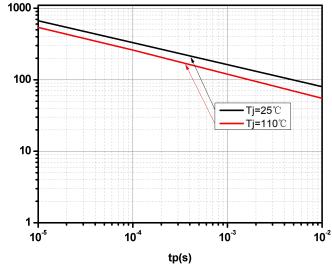
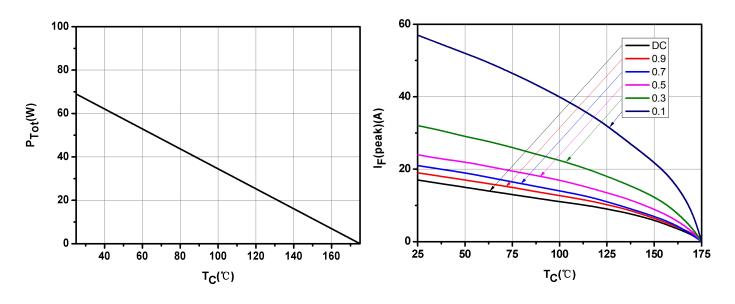


Fig.5-Capacitance Stored Energy

Fig.6-Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)



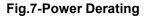


Fig.8-Current Derating

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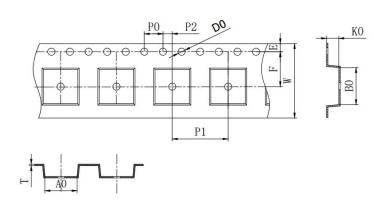


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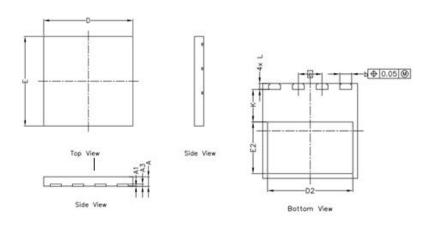
Technical Data Data Sheet N2440, REV.-

Carrier Tape & Reel Specification DFN8×8



SYMBOL	Millimeters		
STMBOL	Min.	Max.	
A0	8.30	8.50	
B0	8.40	8.60	
K0	1.20	1.40	
P0	3.90	4.10	
P1	11.90	12.10	
P2	1.95	2.05	
Т	0.20	0.30	
E	1.65	1.85	
F	7.40	7.60	
D0	1.50	1.60	
D1	1.50		
W	15.70	16.30	

Mechanical Dimensions DFN8×8



SYMBOL	Millimeters		
	Min.	Max.	
A	0.800	0.900	
A1	-	0.050	
A3	0.195	0.211	
D	7.900	8.100	
E	7.900	8.100	
е	2.00 BSC		
b	0.950	1.050	
D2	7.100	7.300	
E2	4.250	4.450	
L	0.400	0.600	
К	2.650	2.850	



Technical Data Data Sheet N2440, REV.-



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